INFORMATION

PRODUCT No.: Q33310F70062200

MODEL: SG-310SCF

INFO. No.: A14-579-3B

DATE: Aug. 19. 2014

SEIKO EPSON CORPORATION

8548 Naka-minowa Minowa-machi Kamiina-gun Nagano-ken 399-4696 Japan

INTRODUCTION

- 1. The contents is subject to change without notice. Please exchange the specification sheets regarding the product's warranty.
- 2. This sheet is not intended to guarantee or provide an approval of implementation of industrial patents.
- 3. We have prepared this sheet as carefully as possible. If you find it incomplete or unsatisfactory in any respect, We would welcome your comments.

This product is compliant with RoHS Directive.

This Product supplied (and any technical information furnished, if any) by Seiko Epson Corporation shall not be used for the development and manufacture of weapon of mass destruction or for other military purposes. Making available such products and technology to any third party who may use such products or technologies for the said purposes are also prohibited.

This product listed here is designed as components or parts for electronics equipment in general consumer use. We do not expect that any of these products would be incorporated or otherwise used as a component or part for the equipment, which requires an extra high reliability, such as satellite, rocket and other space systems, and medical equipment, the functional purpose of which is to keep life.

Product No. / Model

The product No. of this crystal oscillator unit is Q33310F70062200. The model is SG-310SCF.

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[1] Absolute maximum ratings

Parameter	Parameter Symbol		Unit	Note
Supply voltage	Vcc-GND	-0.3 to +4.2	V	
Storage temperature *	T_stg	-40 to +125	°C	Stored as bare product after unpacking.
Input voltage	Vin	-0.3 to Vcc+0.3	V	ST Terminal

^{*} Concerning the frequency change, please refer [8] Environmental and mechanical characteristics.

[2] Operating range

		Value				
Parameter	Symbol	Min.	Тур.	Max.	Unit	Note
Supply voltage	Vcc	2.7	3.3	3.6	V	
Supply voltage	GND	0.0	0.0	0.0	V	
Input voltage	Vin	GND	-	Vcc	V	
Operating temperature	T_use	-40	+25	+85	°C	
Output load condition	L_CMOS	-	-	15	pF	

[•] Start up time(0 % Vcc \rightarrow 90 % Vcc) of power source should be more than 150 μs .

[3] Frequency characteristics

Output frequency (Fo) 50 MHz

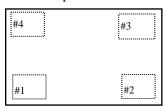
Parameter	Symbol	$Value[1 \times 10^{-6}]$	Note
Frequency tolerance *	F_tol (OSC)	L: ± 50	T_use=-40 °C to +85 °C
Aging	F_aging	l + ን	T_use=+25 °C, Vcc=3.3 V First year

^{*} This includes initial frequency tolerance, temperature characteristics, input voltage characteristics, and load characteristics, but excludes aging.

[•] By-pass capacitor (0.01 μ F to 0.1 μ F) is connected near Vcc between Vcc and GND. (Refer to [12] Recommendable patterning)

[4] Terminal assignment

Top View



Terminal name	Terminal No.	Terminal type.
ST	1	INPUT
GND	2	_
OUT	3	OUTPUT
Vcc	4	_

 \overline{ST} pin: High or open. \rightarrow Specified frequency output = enable.

 \overline{ST} pin: Low. \rightarrow Output is high impedance = disabled.

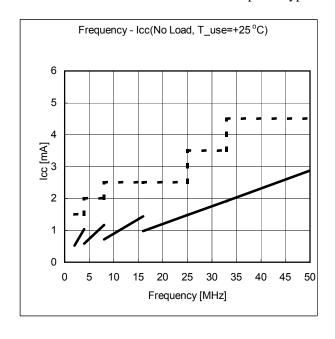
[5] Electrical characteristics

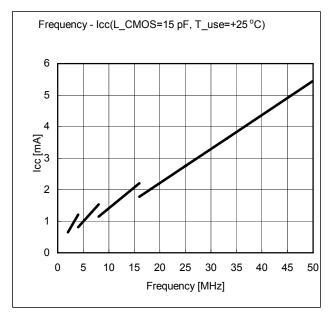
(Please see page 2 [2] Operating range)

		Value			
Parameter	Symbol	Min.	Max.	Unit	Note
Start up time	tosc	-	10	ms	t=0 at 90 % VCC
Current consumption	Icc	-	4.5	mA	No load
Standby current	I_std	-	2.0	μΑ	ST =GND
Output rise time	tr	-	4.0	ns	$20 \% \text{Vcc} \rightarrow 80 \% \text{Vcc}$
Output fall time	tf	1	4.0	ns	$80 \% \text{Vcc} \rightarrow 20 \% \text{Vcc}$
Symmetry	SYM	45	55	%	50 %Vcc Level
High level output voltage	Vон	0.9 Vcc	1	V	Іон = -3 mA
Low level output voltage	Vol	1	0.1 Vcc	V	IoL = 3 mA
High level input voltage	Vih	0.8 Vcc	-	V	ST terminal
Low level input voltage	VIL	-	0.2 Vcc	V	ST terminal
Input current	Іін	-	1.0	μΑ	Vin = Vcc
	IIL	-1.0	-	μΑ	Vin = GND
Output disable time	tstp	-	100	ns	\overline{ST} terminal High \rightarrow Low
Output enable time	tsta	-	10	ms	\overline{ST} terminal Low \rightarrow High
Input pull-up resistance	RUP	4	35	MΩ V _{IN} =GND	
		25	55	kΩ	Vin =0.8 Vcc

Refer to [6] Test circuit [7] Timing chart

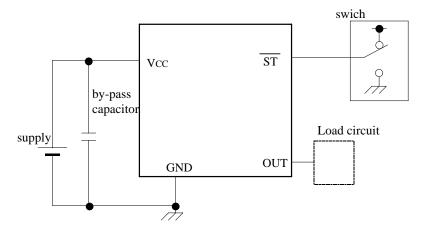
♦ Reference : Current consumption Typ. Value ($V_{CC} = 3.3 \text{ V}$, $T_{use} = +25 ^{\circ}\text{C}$)





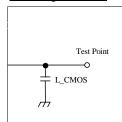
[6] Test circuit

1) Waveform observation

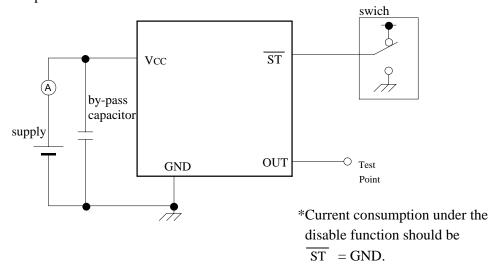


Load circuit

load capacitance



2) Current consumption



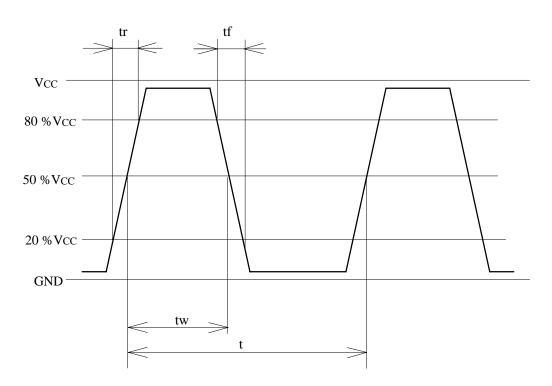
3) Condition

- (1) Oscilloscope
 - Band width should be minimum 5 times higher (wider) than measurement frequency.
 - Probe earth should be placed closely from test point and lead length should be as short as possible.
 - * Recommendable to use miniature socket. (Don't use earth lead.)
- (2) L_CMOS also includes probe capacitance.
- (3) By-pass capacitor (0.01 µF to 0.1 µF) is placed closely between Vcc and GND.
- (4) Use the current meter whose internal impedance value is small.
- (5) Power supply
 - Start up time (0 %Vcc \rightarrow 90 %Vcc) of power source should be more than 150 μ s.
 - Impedance of power supply should be as lowest as possible.

[7] Timing chart

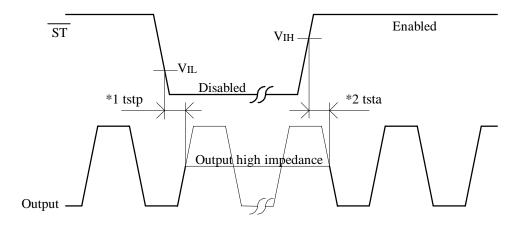
1) C-MOS load

$$SYM = tw/t \times 100 (\%)$$



2) ST function and timing

ST function Osc. circuit		Output status		
High or Open Oscillation		Specified frequency is output: Enable		
Low	Oscillation stop	Output becomes high impedance : Disable		



*1 The time taken from $\overline{ST} = VIL$ to output = Disable (high impedance)

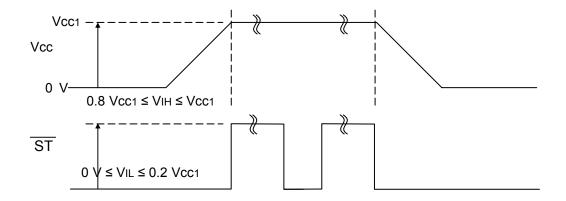
*2 The time taken from \overline{ST} =VIH to output = Start

Output start : Voh \geq 0.8 % Vcc, Vol \leq 0.2 % Vcc, Fout = Fo \pm 1 000×10⁻⁶

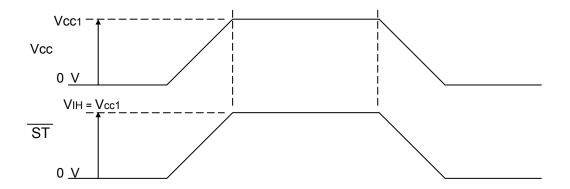
3) ST Control timing

ST function is used on the voltage below supply voltage.

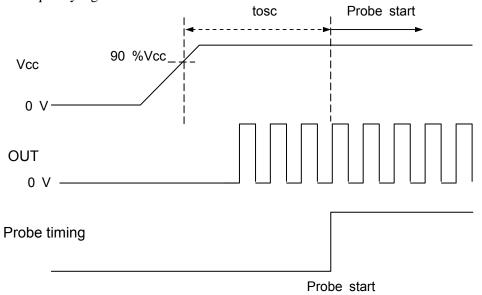
ST control timing differs from Vcc control timing



ST terminal is connected to Vcc terminal



4) Timing of an output frequency signal



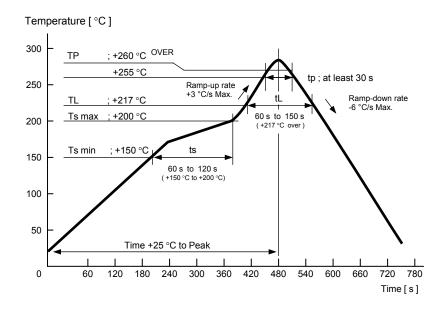
[8] Environmental and mechanical characteristics

(The company evaluation condition We evaluate it by the following examination item and examination condition.)

		Valu	e *1	Test Conditions
No.	Item	$\Delta f / f *2$	Electrical	
		$[1 \times 10^{-6}]$	characteristics	
1	High temperature storage	*3 ±50		+125 °C × 1 000 h
2	Low temperature storage	*3 ± 10		-40 °C × 1 000 h
3	High temperature bias	*3 ± 20		+85 °C × V Max. × 1 000 h
4	Low temperature bias	*3 ± 10		-40 °C × V Max. × 1 000 h
5	Temperature humidity bias	*3 ±20		+85 °C × 85 %RH × V Max. × 1 000 h
6	Temperature cycle	*3 ± 20		$-40 ^{\circ}\text{C} \leftrightarrow +125 ^{\circ}\text{C}$
	Temperature cycle	3 ± 20		30 min. at each temperature 100 cycles
7	Resistance to soldering heat	± 10		Convection reflow soldering furnace (3 time) Ref. IPC/JEDEC J-STD-020D.1
8	Shock	± 5	Satisfy Item [5] after test.	100 g dummy Jig (SE Standard) drop from 1 500 mm height on the Concrete 3 directions 10 times.
9	Vibration	±10		10 Hz to 55 Hz amplitude 0.75 mm 55 Hz to 500 Hz acceleration 98 m/s ² 10 Hz \rightarrow 500 Hz \rightarrow 10 Hz 15 min./cycle 6 h (2 hours, 3 directions)
10	Seal	1×10^{-9} Pa·m ³ /s		He leakage detector
11	Pull - off	No peeling-off at a solder part		10 N press for 10 s ± 1 s Ref. EIAJ ED-4702
12	Solderability	Termination must be 95 % covered with fresh solder		Dip termination into solder bath at +235 °C ± 5 °C for 5 s. (Using Rosin Flux)

< Notes >

Convection reflow condition (Ref. IPC/JEDEC J-STD-020D.1)



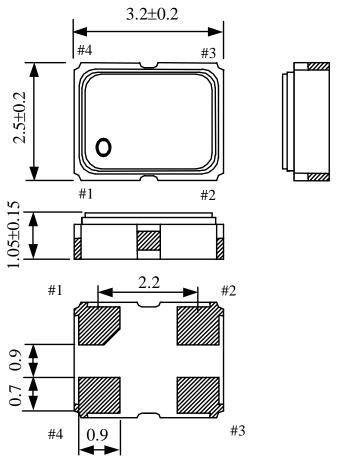
^{*1} Each test done independently.

^{*2} Measuring 2 h to 24 h later leaving in room temperature after each test.

^{*3} Initial value shall be measured after 24 h storage at room temperature after pre-conditioning. Pre-conditioning: Reflow (3 time)

[9] Dimensions and marking layout

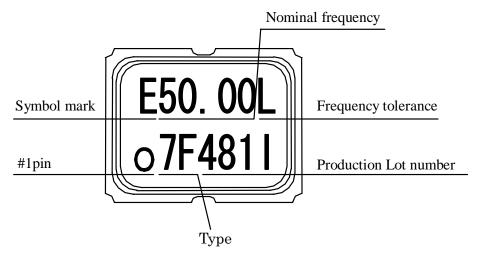
1) Dimensions



Terminal treatment : Au plating

Unit: mm

2) Marking layout



- ♦ The above marking layout shows only marking contents and their approximate position and it is not for font, size and exact position.
- ♦ Output frequency shall indicate 5 digits (include decimal point), if the value of frequency over 5 digits, the least significant digits will be omitted.

[10] Notes

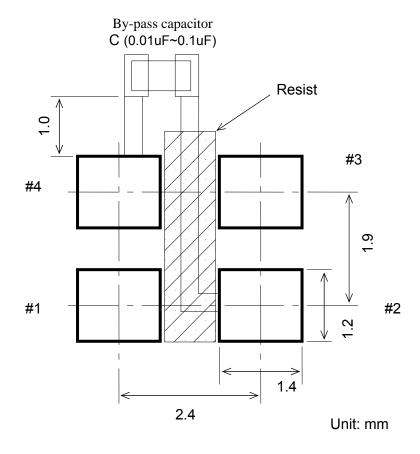
- 1) This device is made with C-MOS IC.

 Please take necessary precautions to prevent damage due to electrical static discharge.
- 2) SEIKO EPSON recommends a 0.01 μF to 0.1 μF capacitor must be connected near Vcc between Vcc and GND to obtain stable operation and protect against power line ripple. (Refer to [12] Recommendable patterning)
- 3) Vcc and GND pattern shall be as large as possible so that high frequency impedance shall be small.
- 4) SEIKO EPSON cannot recommend to put filtering element into power line so as to reduce noise. Oscillator might be unstable oscillation because high frequency impedance of power line become higher. When use filtering element, please verify electrical construction and or element's spec.
- 5) SEIKO EPSON doesn't recommend to power on from intermediate electric voltage or extreme fast power on, Those powering conditions may cause no oscillation or abnormal oscillation.
- 6) Power ripple: 200 mV P-P max. Start up time (0 %Vcc \rightarrow 90 %Vcc) of power source should be more than 150 μ s.
- 7) A long output line may cause irregular output, so try to make the output line as short as possible.
- 8) Other high-level signal lines may cause incorrect operation, so please do not place high level signal line close to this device.
- 9) This device contains a crystal resonator, so please don't expose excessive shock or vibration. SEIKO EPSON recommends store device under normal temperature and humidity to keep the specification.
- 10) An automatic insertion is available, however, the internal crystal resonator might be damaged in case that too much shock or vibration is applied by machine condition.
 Be sure to check your machine condition in advance.
- 11) Ultrasonic cleaning can be used on the SG-310SCF, however, since the oscillator might be damaged under some conditions, please exercise in advance.
- 12) SEIKO EPSON recommends to use and store under room temperature and normal humidity to secure frequency accuracy and prevent moisture.
- 13) ST -pin has pull-up resistor internally. The resistor value is switched depending on input voltage. Please refer to electrical characteristics.

[11] Recommendable patterning

The soldering pad sample indicated as like following:

Soldering position (Unit: mm)



TAPING SPECIFICATION

I. Application

This standard will apply to 3.2×2.5 Ceramic package.

Spec: CE package

II. Contents

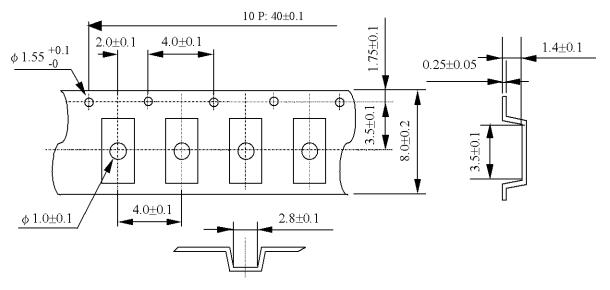
Item No.	Item	Page
[1]	Taping specification	1 to 2
[2]	Inner carton	3
[3]	Shipping carton	
[4]	Marking	4
[5]	Quantity	
[6]	Storage environment	
[7]	Handling	

[1] Taping specification

Subject to 「EIA-481」 and 「IEC-60286」

(1) Tape dimensions

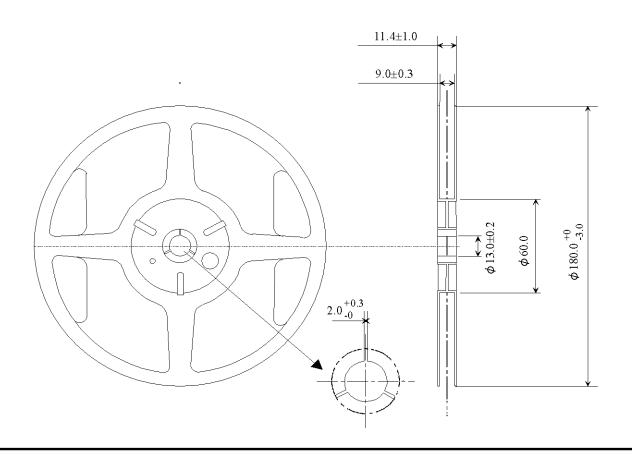
 $\label{eq:material} \begin{tabular}{ll} Material of the carrier tape: PS \\ Material of the top tape: $PET+PE$ \\ \end{tabular}$

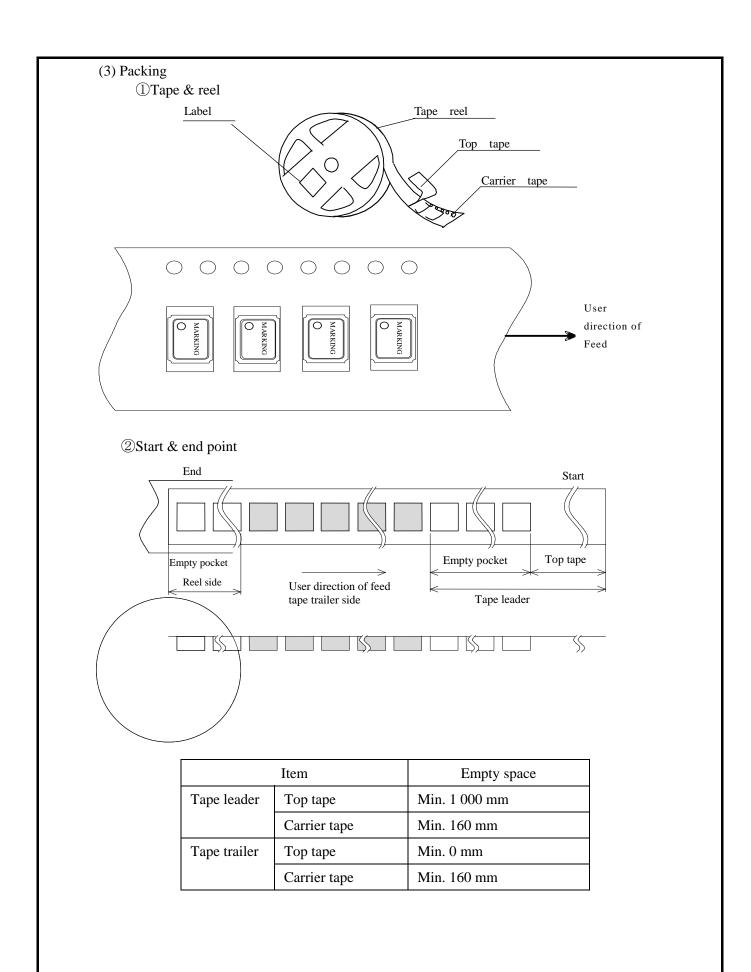


Unit: mm

(2) Reel dimensions

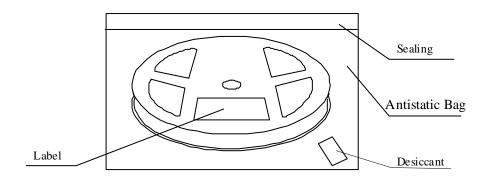
Material of the reel: Conductive polystyrene



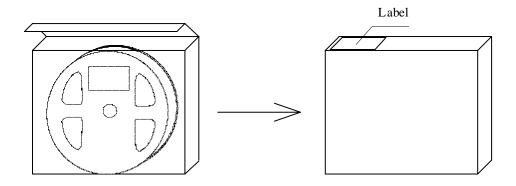


[2] Inner carton

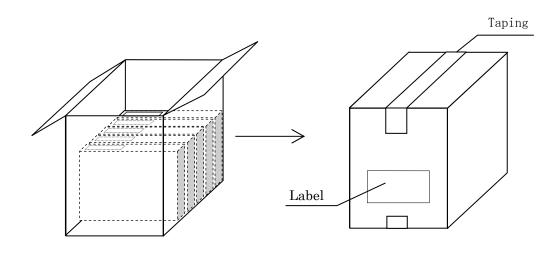
a) Packing to antistatic bag



b) Packing to inner carton



(3) Shipping carton



[4] Marking

- (1) Reel marking
 - Reel marking shall consist of:
 - 1) Parts name
 - 2) Quantity
 - 3) Manufacturing date or symbol
 - 4) Manufacturer's date or symbol
 - 5) Others (if necessary)
- (2) Inner carton marking
 - · Same as reel marking.
- (3) Shipping carton marking
 - Shipping carton marking shall consist of :
 - 1) Parts name
 - 2) Quantity
- [5] Quantity
 - 2,000 pcs./reel
- [6] Storage environment
 - (1) Before open the packing, we recommend to keep less than $+30\,^{\circ}\text{C}$ and $85\,^{\circ}\text{RH}$ of Humidity, and to use it less than 6 months after delivery.
 - (2) We recommend to open Package in immediately before use. After open Package, We recommend to keeps less than 6 month. No need dry air before soldering work if it is less than temperature +30 °C, 85 humidity %RH.
 - (3) Not to expose the sun.
 - (4) Not to storage with some erosive chemicals.
 - (5) Nothing is allowed to put on the reel or carton to prevent mechanical damage.
- [7] Handling
 - To handle with care to prevent the damage of tape, reel and products.

No. SG310S*F - 00 - AEE - 5 CRYSTAL OSCILLATOR: SG-310S*F

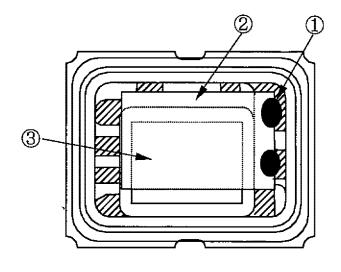
Manufacturing process chart Section In Charge Standards Inspection, Instruments Inspection Record Control Item Methods Inspection Section Purchasing Specification Appearance Dimension Microscope Sampling Data sheet Incoming Inspection Standard · · · In-coming Inspection Malaysia Plant Microscope Manufacturing Instruction Appearance Sampling Data sheet (Production Section) Peeling Strength Scratch CI Meter (3) Frequency Base Set Malaysia Plant Microscope Data sheet 3 Manufacturing Instruction Appearance Sampling (Production Section) Sheet Parts Mounting (IC) 2 Deposition Malaysia Plant Manufacturing Instruction Appearance Microscope Sampling Data sheet (Production Section) Wire Bonding 5 Malaysia Plant Manufacturing Instruction Sampling Data sheet Bonding strength Gauge (Production Section) Appearance Microscope 100% Inspection Crystal-Mounting Malaysia Plant Manufacturing Instruction Appearance Microscope 100% Inspection Data sheet (Production Section) Sheet Malaysia Plant Manufacturing Instruction Microscope Data sheet Annealing Appearance Sampling (Production Section) Sheet Malaysia Plant Manufacturing Instruction Frequency Adjusting (Production Section) Sheet (Crystal) Malaysia Plant Manufacturing Instruction Appearance Microscope Sampling Data sheet 9 Temporary Hermetic Sealing (Production Section) Sheet Malaysia Plant Microscope Manufacturing Instruction Appearance Sampling Data sheet (10) Hermetic Sealing (Production Section) Sheet Frequency Counter Sampling 11 Malaysia Plant Manufacturing Instruction (11) High Temp Treatment (Production Section) Sheet 12 Malaysia Plant Manufacturing Instruction Leakage Inspection Measuring equipment 100% Inspection Data sheet Fine-Leakage (Production Section) Sheet 13 Malaysia Plant Manufacturing Instruction Leakage Inspection Data sheet Measuring equipment 100% Inspection Gross-Leakage (Production Section) Sheet 14 Malaysia Plant Manufacturing Instruction Temp Characteristic Measuring equipment Sampling Data sheet 14 Temp Characteristic (Production Section) Sheet Inspection 15 Malaysia Plant Manufacturing Instruction Characteristic Inspection Measuring equipment 100% Inspection Data sheet (15) LDL Inspection (Production Section) Malaysia Plant Manufacturing Instruction Electrical Characteristic Measuring equipment 100% Inspection Data sheet 16 Electrical Characteristic (Production Section) Sheet Manufacturing Instruction 17 Malaysia Plant Appearance Visual Inspection Sampling Data sheet (17) Marking (Production Section) 18 Malaysia Plant Manufacturing Instruction Data sheet Microscope Sampling Appearance Visual Inspection (Production Section) 19 Malaysia Plant Delivery Specifications Electrical Characteristic Data sheet Measuring equipment Sampling (19) Outgoing Inspection (Inspection Section) Outgoing Inspection Standard Appearance Visual Inspection (20) Taping 20 Malaysia Plant Manufacturing Instruction Tape peeling Strength Peeling strength Sampling Data sheet (Production Section) test machine Packing 21 Malaysia Plant Manufacturing Instruction Customers Delivery (Production Control Sheet Type Slip Section) Daily Shipping List Ouantity

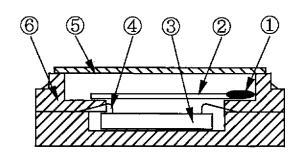
12.7.2

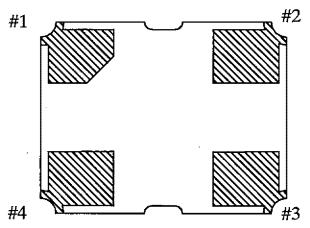
No. SG310S*F - 00 - ASE - 2 CRYSTAL OSCILLATOR: SG-310S*F

'05.10.3 Manufacturing process chart No. Section In Charge Standards Inspection, Instruments Inspection Record Control Item Methods Purchasing Specification Appearance Dimension 1 Inspection Section Microscope Sampling Data sheet Incoming Inspection Standard · In-coming Inspection 2 China Plant Manufacturing Instruction Appearance Microscope Sampling Data sheet (Production Section) Peeling Strength Scratch 3 Base Frequency CI Meter China Plant 3 Manufacturing Instruction Appearance Microscope Sampling Data sheet (Production Section) 2 Deposition 4 Parts Mounting (IC) 4 China Plant Manufacturing Instruction Appearance Microscope Sampling Data sheet (Production Section) Wire Bonding 5 Manufacturing Instruction China Plant Bonding strength Gauge Sampling Data sheet (Production Section) Sheet Appearance Microscope 100% Inspection 6 China Plant Manufacturing Instruction Appearance Microscope 100% Inspection Data sheet Crystal-Mounting (Production Section) China Plant Manufacturing Instruction Appearance Microscope Sampling Data sheet (Production Section) Annealing 8 China Plant Manufacturing Instruction (Production Section) Sheet Frequency Adjusting China Plant Manufacturing Instruction Appearance Visual Inspection (Crystal) 100% Inspection Data sheet (Production Section) (9 Cleaning 10 China Plant Manufacturing Instruction Арреаталсе Microscope Sampling Data sheet (Production Section) Temporary Hermetic Sealing 11 China Plant Manufacturing Instruction Appearance Microscope Sampling Data sheet (Production Section) Frequency Counter Sampling (11) Hermetic Sealing 12 China Plant Manufacturing Instruction (Production Section) Sheet High Temp Treatment 13 China Plant Manufacturing Instruction Leakage Inspection Measuring equipment Data sheet 100% Inspection (Production Section) Sheet Fine-Leakage 14 China Plant Manufacturing Instruction Leakage Inspection Measuring equipment 100% Inspection Data sheet (Production Section) Sheet Gross-Leakage 15 China Plant Manufacturing Instruction Temp Characteristic Measuring equipment Sampling Data sheet (Production Section) (15) Temp Characteristic Inspection China Plant 16 Manufacturing Instruction Characteristic Inspection Measuring equipment 100% Inspection Data sheet LDL Inspection (Production Section) Sheet 17 China Plant Manufacturing Instruction Electrical Characteristic Measuring equipment Data sheet 100% Inspection Electrical Characteristic (Production Section) 18 China Plant Manufacturing Instruction Appearance Visual Inspection Sampling Data sheet (18) Marking (Production Section) 19 China Plant Manufacturing Instruction Appearance Data sheet Microscope Sampling Visual Inspection (Production Section) Sheet 20 China Plant **Delivery Specifications** Electrical Characteristic Measuring equipment Sampling Data sheet Outgoing Inspection (Inspection Section) Outgoing Inspection Standard Appearance Visual Inspection [21] Taping 21 Chaina Plant Manufacturing Instruction Tape peeling Strength Data sheet Peeling strength Sampling (Production Section) test machine **Packing** 22 Chaina Plant Manufacturing Instruction Customers Delivery (Production Control Sheet Slip Type Section) Daily Shipping List Quantity

Structure diagram SG-310S*F







	LIST	
	Name of part	Material
Θ	Crystal adhesive	Ag paste
0	Crystal chip	AT cut
3	IC .	C-MOS
	IC conductive adhesive	Ag paste
4	Bonding wire	Au
6	Сар	Cover
6	Package	Ceramic (Al ₂ 0 ₂)
·		

RELIABILITY TEST DATA

Product Name: SG-310 Series

The Company evaluation condition

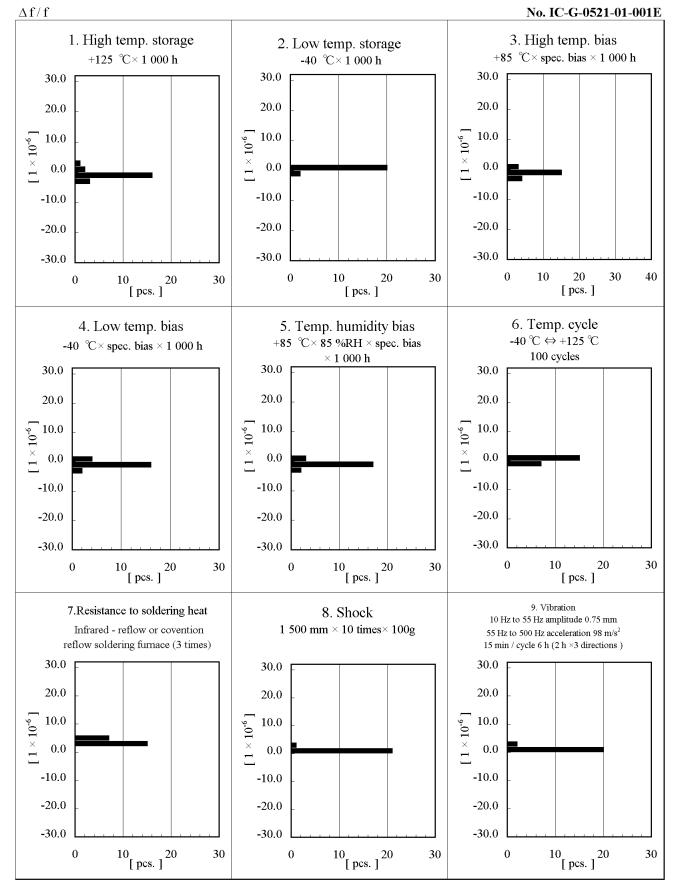
We evaluate environmental and mechanical characteristics by the following test condition . No. IC-G-0521-01-001E

			VAL	UE *1	TEST	FAIL
No.	ITEM	TEST CONDITIONS	$\Delta f/f *2$	Electrical	Qty	Qty
			$[1 \times 10^{-6}]$	characteristics	[n]	[n]
1	High temperature storage	+125 °C × 1 000 h	*3 ± 50		22	0
2	Low temperature storage	-40 °C × 1 000 h	*3 ± 10		22	0
3	High temperature bias	+85 °C × spec. bias × 1 000 h	*3 ± 20		22	0
4	Low temperature bias	-40 °C × spec. bias ×1 000 h	*3 ± 10		22	0
5	Temperature humidity bias	+85 °C × 85 %RH × spec. bias × 1 000 h	*3 ± 20	Satisfy specification	22	0
6	Temperature cycle	-40 °C ⇔ +125 °C 30 min. at each temperature 100 cycles	*3 ± 20	after test	22	0
7	Resistance to soldering heat	Infrared - reflow or convention reflow soldering furnace (3 times)	± 10		22	0
8	Shock	100g dummy Jig(Epson Toyocom Standard) drop from 1500mm height on the Concrete 3 directions 10 times	± 5		22	0
9	Vibration	10 Hz to 55 Hz amplitude 0.75 mm 55 Hz to 500 Hz acceleration 98 m/s ² 10 Hz → 500 Hz → 10 Hz 15 min./cycle 6 h (2 hours, 3 directions)	± 10		22	0
10	Seal	He leakage detector	1 × 10 ⁻⁹ Pa•	m ³ /s	11	0
11	Pull - off	10 N press for 10 s ± 1 s Ref.EIAJ ED-4702	part	off at a solder	11	0
12	Solderability	Dip termination into solder bath at $+235 ^{\circ}\text{C} \pm 5 ^{\circ}\text{C}$ for 5s . (Using Rosin Flux)	l	must be 95 % n fresh solder	11	0

Notes

- 1. *1 Each test done independently.
- 2. *2 Measuring 2 h to 24 h later leaving in room temperature after each test.
- 3. *3 Pre conditionings Initial value shall be after 24 h at room temperature after pre-conditioning.

Product Name: SG-310 Series



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